## NSN 5962-01-181-2855

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View Online at https://aerobasegroup.com/nsn/5962-01-181-2855

| Body Length:   |
|--|
| 0.840 inches   |
| Body Width:  |
| Between 0.220 inches and 0.310 inches  |
| Body Height:   |
| Between 0.140 inches and 0.185 inches  |
| Maximum Power Dissipation Rating:  |
| 794.0 milliwatts   |
| Operating Tempurature Range:   |
| -55.0/+125.0 degrees celsius   |
| Storage Tempurature Range:   |
| -65.0/+150.0 degrees celsius   |
| Features Provided:   |
| Hermetically sealed and burn in and schottky and monolithic and programmed   |
| Inclosure Material:  |
| Ceramic  |
| Inclosure Configuration:   |
| Dual-in-line   |
| Output Logic Form:   |
| Transistor-transistor logic  |
| Input Circuit Pattern:   |
| 10 input   |
| Case Outline Source And Designator:  |
| D-2 mil-m-38510  |
| Current Rating Per Characteristic:   |
| 140.00 milliamperes reverse current, dc absolute   |
| Terminal Surface Treatment:  |
| Solder   |
| Voltage Rating And Type Per Characteristic:  |
| -0.5 volts power source and 7.0 volts power source   |
| Time Rating Per Chacteristic:  |
| 85.00 nanoseconds delay  |
| Memory Device Type:  |
| Prom   |
| Test Data Document:  |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And Quantity:  |
| 16 printed circuit   |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
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Demilitarization:

Yes - demil/mli

Fiig:

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